

General Description

The WSD4080DN56 is the highest performance trench N-ch MOSFET with extreme high cell density , which provide excellent RDSON and gate charge for most of the synchronous buck converter applications .

The WSD4080DN56 meet the RoHS and Green Product requirement 100% EAS guaranteed with full function reliability approved.

Features

- Advanced high cell density Trench technology
- Super Low Gate Charge
- Excellent CdV/dt effect decline
- 100% EAS Guaranteed
- Green Device Available

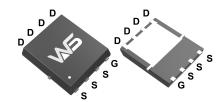
Product Summery

BVDSS	RDSON	ID
40V	4.5mΩ	85A

Applications

- Battery protection
- Load switch
- Uninterruptible power supply

DFN5X6-8 Pin Configuration





Absolute Maximum Ratings (Tc=25°Cunless otherwise noted)

Symbol	Parameter	Rating	Units	
VDS	Drain-Source Voltage	40	V	
Vgs	Gate-Source Voltage	±20	V	
In@Tc=25°C	Continuous Drain Current, Vos @ 10V1	85	А	
In@Tc=100°C	Continuous Drain Current, Vos @ 10V1	58	А	
Ірм	Pulsed Drain Current ₂	100	А	
EAS	Single Pulse Avalanche Energy ₃	110.5	mJ	
las	Avalanche Current	47	А	
Pp@Tc=25°C	Total Power Dissipation4	52.1	W	
Тѕтс	Storage Temperature Range	-55 to 150	°C	
Tu	Operating Junction Temperature Range -55 to 150		°C	
Reja	Thermal Resistance Junction-Ambient 1	62	°C/W	
Rejc	Thermal Resistance Junction-Case ₁	2.4	°C/W	



Electrical Characteristics (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Min.	Тур.	Max.	Unit
BVDSS	Drain-Source Breakdown Voltage	Vgs=0V , Ip=250uA	40			٧
Rds(on)	Static Drain-Source On-Resistance ₂	Vgs=10V , Ip=10A		4.5	6.5	· mΩ
		Vgs=4.5V , ID=5A		6.4	8.5	
V _{GS(th)}	Gate Threshold Voltage	Vgs=Vds, Id=250uA	1.0		2.5	٧
Ipss	Drain-Source Leakage Current	V _{DS} =32V , V _{GS} =0V , T _J =25°C			1	- uA
1055		V _{DS} =32V , V _{GS} =0V , T _J =55°C			5	
lgss	Gate-Source Leakage Current	Vgs=±20V , Vps=0V			±100	nA
gfs	Forward Transconductance	V _{DS} =10V , I _D =5A		27		S
Q_g	Total Gate Charge (4.5V)	V _{DS} =20V , V _{GS} =4.5V , I _D =10A		20		nC
Qgs	Gate-Source Charge			5.8		
Qgd	Gate-Drain Charge			9.5		
T _{d(on)}	Turn-On Delay Time	V _{DD} =15V , V _{GS} =10V R _G =3.3Ω I _D =1A		15.2		ns
Tr	Rise Time			8.8		
T _{d(off)}	Turn-Off Delay Time			74		
Tf	Fall Time			7		
Ciss	Input Capacitance	V _{DS} =15V , V _{GS} =0V , f=1MHz		2354		pF
Coss	Output Capacitance			215		
Crss	Reverse Transfer Capacitance			175		
Is	Continuous Source Current _{1,5}	V _G =V _D =0V , Force Current			70	Α
VsD	Diode Forward Voltage ₂	Vgs=0V , Is=1A , T _J =25°C			1	V

Note:

- 1. The data tested by surface mounted on a 1 inch2 FR-4 board with 2OZ copper.
- 2.The data tested by pulsed , pulse width \leqq 300us , duty cycle \leqq 2%
- 3.The EAS data shows Max. rating . The test condition is VDD=25V,VGS=10V,L=0.1mH,IAS=47A
- 4.The power dissipation is limited by 150°C junction temperature
- 5. The data is theoretically the same as ID and IDM, in real applications, should be limited by total power dissipation.



Typical Characteristics

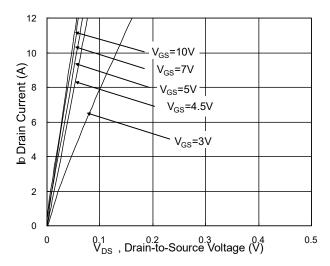


Fig.1 Typical Output Characteristics

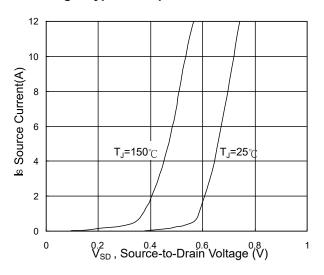


Fig.3 Forward Characteristics of Reverse

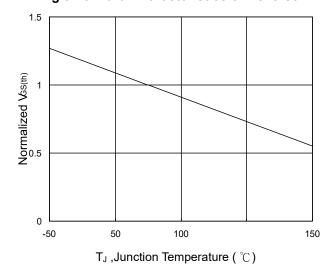


Fig.5 Normalized $V_{\text{GS(th)}}$ vs. T_{J}

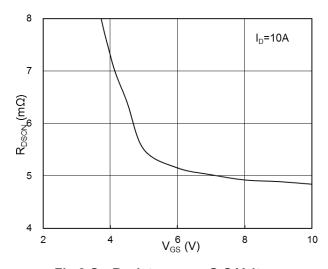


Fig.2 On-Resistance vs. G-S Voltage

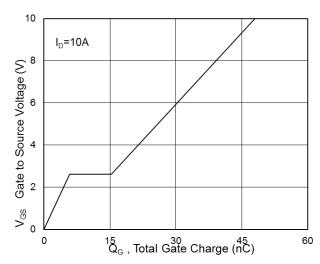


Fig.4 Gate-Charge Characteristics

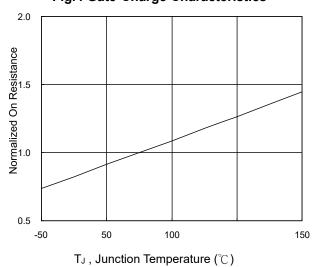
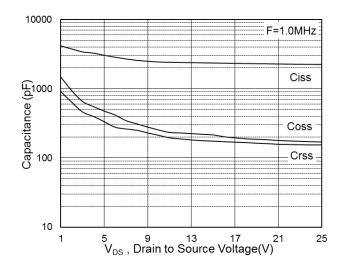


Fig.6 Normalized R_{DSON} vs. T_J





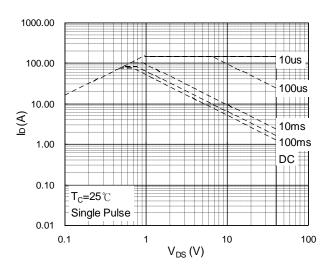


Fig.7 Capacitance

Fig.8 Safe Operating Area

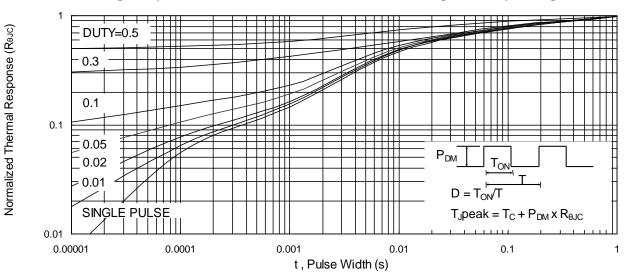


Fig.9 Normalized Maximum Transient Thermal Impedance

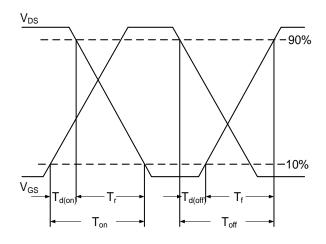


Fig.10 Switching Time Waveform

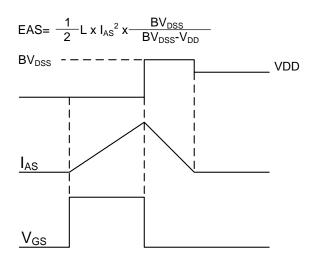


Fig.11 Unclamped Inductive Switching Wave



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